

D. Thin Film Process Technology 분과

2021년 1월 27일(수), 10:45-12:15 / 채널 A

[WA2-D] Thin Film Process $\,\mathrm{I}\,$

좌장: 김우희 교수 (한양대학교), 엄태용 박사 (KRICT)

WA2-D-1 10:45-11:00	Comparative Study between Cyclopentadienyl Titanium Trimethoxide and Cyclopentadienyl Titanium Tris(dimethylamide) for Atomic Layer Deposition of Titanium Oxide Hye-Lee Kim, Romel Hidayat, Yeongchan Choi, Jaemin Kim, and Won-Jun Lee Department of Nanotechnology and Advanced Materials Engineering, Sejong University
WA2-D-2 11:00-11:15	수소 플라즈마를 이용한 저온(≤ 150 °C) 고품질 sputtered SiO₂ 박막 형성 Taewon Seo, Gilsu Jeon, Hyuk Park, Juyoung Yun, Seongmin Park, Suwon Seong, and Yoonyoung Chung Department of Electrical Engineering, POSTECH
WA2-D-3 11:15-11:30	Reaction Mechanism of Atomic Layer Deposition of SiO ₂ Using Bis(diethylamino)silane and Ozone Hyeonsu Roh, Hye-Lee Kim, Donggeon Shin, and Won-Jun Lee Department of Nanotechnology and Advanced Materials Engineering, Sejong University
WA2-D-4 11:30-11:45	Area-selective Atomic Layer Deposition Assisted by Short-chain Alkanethiols Self-assembled Monolayers Jeongbin Lee, Jinseon Lee, Jeong-Min Lee, Tae Joo Park, and Woo-Hee Kim Department of Materials Science and Chemical Engineering, Hanyang University
WA2-D-5 11:45-12:15	[초청] Directional Ionic Transport across the Oxide Interface Enables Low-temperature Epitaxy of Rutile TiO ₂ Junwoo Son Department of Materials Science and Engineering, POSTECH